

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

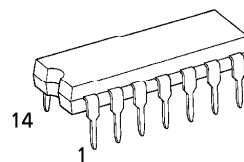
TC4081BP, TC4081BF, TC4081BFN

TC4081B QUAD 2 INPUT AND GATE

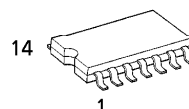
TC4081B is positive logic AND gates with two inputs respectively.

Since all the outputs of these gates are equipped with the buffer circuits of inverters, the input/output propagation characteristic has been improved and variation of propagation time caused by increase of load capacity is kept minimum.

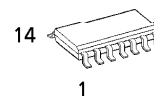
(Note) The JEDEC SOP (FN) is not available in Japan.



P (DIP14-P-300-2.54)
Weight : 0.96g (Typ.)



F (SOP14-P-300-1.27)
Weight : 0.18g (Typ.)



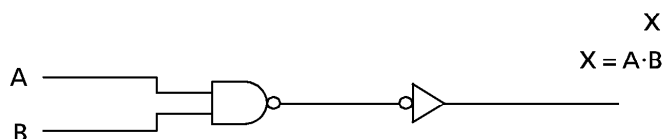
FN (SOL14-P-150-1.27)
Weight : 0.12g (Typ.)

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V_{DD}	$V_{SS} - 0.5 \sim V_{SS} + 20$	V
Input Voltage	V_{IN}	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	V
Output Voltage	V_{OUT}	$V_{SS} - 0.5 \sim V_{DD} + 0.5$	V
DC Input Current	I_{IN}	± 10	mA
Power Dissipation	P_D	300 (DIP) / 180 (SOIC)	mW
Operating Temperature Range	T_{ope}	$-40 \sim 85$	°C
Storage Temperature Range	T_{stg}	$-65 \sim 150$	°C

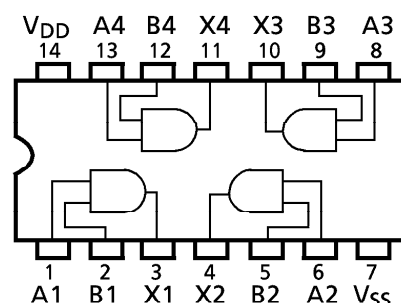
LOGIC DIAGRAM

1/4 TC4081B



PIN ASSIGNMENT (TOP VIEW)

TC4081B



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RECOMMENDED OPERATING CONDITIONS ($V_{SS} = 0V$)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
DC Supply Voltage	V_{DD}		3	—	18	V
Input Voltage	V_{IN}		0	—	V_{DD}	V

STATIC ELECTRICAL CHARACTERISTICS ($V_{SS} = 0V$)

CHARACTERISTIC	SYM-BOL	TEST CONDITION	V_{DD} (V)	- 40°C		25°C			85°C		UNIT
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Output Voltage	V_{OH}	$ I_{OUT} < 1\mu A$ $V_{IN} = V_{SS}, V_{DD}$	5	4.95	—	4.95	5.00	—	4.95	—	V
			10	9.95	—	9.95	10.00	—	9.95	—	
			15	14.95	—	14.95	15.00	—	14.95	—	
Low-Level Output Voltage	V_{OL}	$ I_{OUT} < 1\mu A$ $V_{IN} = V_{SS}, V_{DD}$	5	—	0.05	—	0.00	0.05	—	0.05	V
			10	—	0.05	—	0.00	0.05	—	0.05	
			15	—	0.05	—	0.00	0.05	—	0.05	
Output High Current	I_{OH}	$V_{OH} = 4.6V$	5	- 0.61	—	- 0.51	- 1.0	—	- 0.42	—	mA
		$V_{OH} = 2.5V$	5	- 2.50	—	- 2.10	- 4.0	—	- 1.70	—	
		$V_{OH} = 9.5V$	10	- 1.50	—	- 1.30	- 2.2	—	- 1.10	—	
		$V_{OH} = 13.5V$	15	- 4.00	—	- 3.40	- 9.0	—	- 2.80	—	
		$V_{IN} = V_{SS}, V_{DD}$									
Output Low Current	I_{OL}	$V_{OL} = 0.4V$	5	0.61	—	0.51	1.2	—	0.42	—	mA
		$V_{OL} = 0.5V$	10	1.50	—	1.30	3.2	—	1.10	—	
		$V_{OL} = 1.5V$	15	4.00	—	3.40	12.0	—	2.80	—	
		$V_{IN} = V_{SS}, V_{DD}$									
Input High Voltage	V_{IH}	$V_{OUT} = 0.5V, 4.5V$	5	3.5	—	3.5	2.75	—	3.5	—	V
		$V_{OUT} = 1.0V, 9.0V$	10	7.0	—	7.0	5.50	—	7.0	—	
		$V_{OUT} = 1.5V, 13.5V$	15	11.0	—	11.0	8.25	—	11.0	—	
		$ I_{OUT} < 1\mu A$									
Input Low Voltage	V_{IL}	$V_{OUT} = 0.5V, 4.5V$	5	—	1.5	—	2.25	1.5	—	1.5	V
		$V_{OUT} = 1.0V, 9.0V$	10	—	3.0	—	4.50	3.0	—	3.0	
		$V_{OUT} = 1.5V, 13.5V$	15	—	4.0	—	6.75	4.0	—	4.0	
		$ I_{OUT} < 1\mu A$									
Input Current	"H" Level	I_{IH}	$V_{IH} = 18V$	18	—	0.1	—	10^{-5}	0.1	—	μA
	"L" Level	I_{IL}	$V_{IL} = 0V$	18	—	- 0.1	—	$- 10^{-5}$	- 0.1	—	
Quiescent Supply Current	I_{DD}	$V_{IN} = V_{SS}, V_{DD}^*$	5	—	0.25	—	0.001	0.25	—	7.5	μA
			10	—	0.50	—	0.001	0.50	—	15.0	
			15	—	1.00	—	0.002	1.00	—	30.0	

* All valid input combinations.

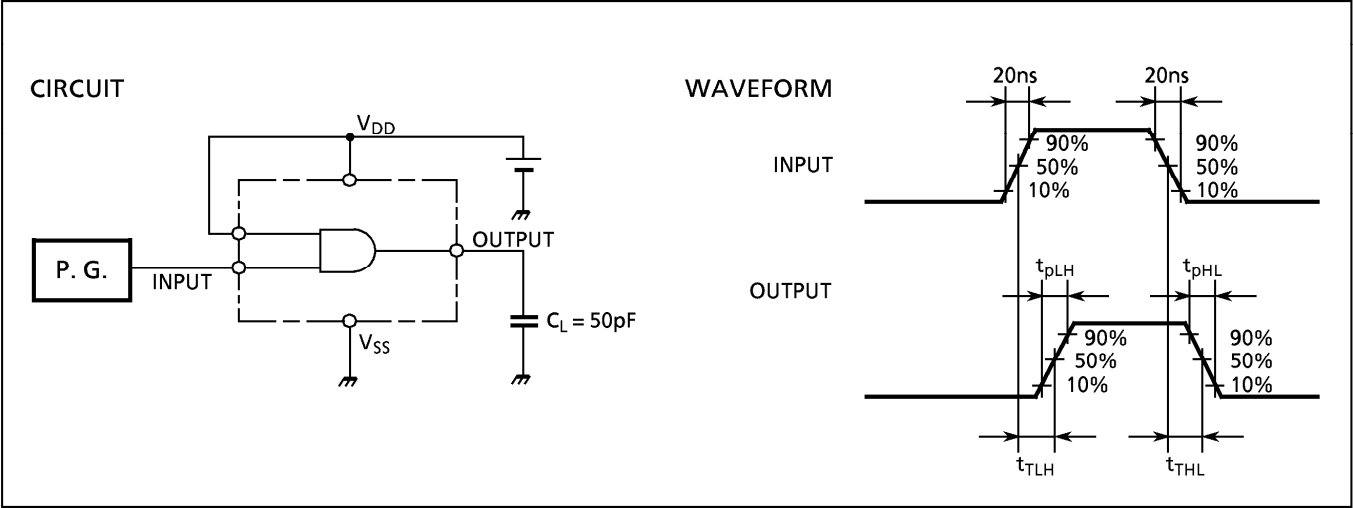
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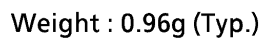
DYNAMIC ELECTRICAL CHARACTERISTICS (Ta = 25°C, Vss = 0V, CL = 50pF)

CHARACTERISTIC	SYMBOL	TEST CONDITION	VDD(V)	MIN.	TYP.	MAX.	UNIT
Output Transition Time	tTLH		5	—	70	200	ns
			10	—	35	100	
			15	—	30	80	
Output Transition Time	tTHL		5	—	70	200	
			10	—	35	100	
			15	—	30	80	
Propagation Delay Time	tpLH		5	—	65	200	
			10	—	30	100	
			15	—	25	80	
Propagation Delay Time	tpHL		5	—	65	200	
			10	—	30	100	
			15	—	25	80	
Input Capacitance	CIN			—	5	7.5	pF

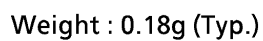
CIRCUITS AND WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS



Unit in mm



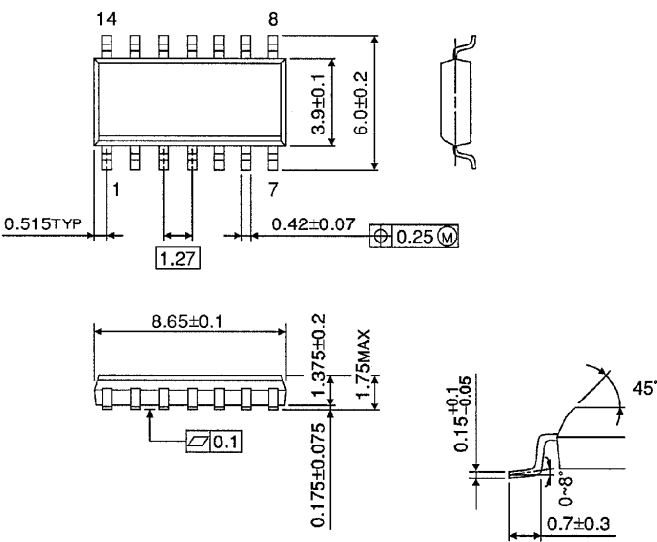
Unit in mm



SOP 14PIN (150mil BODY) OUTLINE DRAWING (SOL14-P-150-1.27)

Unit in mm

(Note) This package is not available in Japan.



Weight : 0.12g (Typ.)